

### STMUX1800L

## 16- to 8-bit MUX/DEMUX for gigabit Ethernet LAN switch with LED switch and enhanced ESD protection

#### **Features**

■ Low R<sub>ON</sub>: 4.0 Ω typical

■ V<sub>CC</sub> operating range: 3.0 to 3.6 V

■ Enhanced ESD protection: > 8 kV (contact) and 15 kV (HBM)

■ Channel on capacitance: 9.5 pF typical

Switching time speed: 9 ns

Near to zero propagation delay: 250 ps
 Very low crosstalk: -45 dB at 250 MHz

Bit-to-bit skew: 200 ps

> 600 MHz -3 dB typical bandwidth (or data frequency)

■ Three SPDT switches for LED support

 Rail-to-rail switching on data I/O ports (0 V to 5 V)

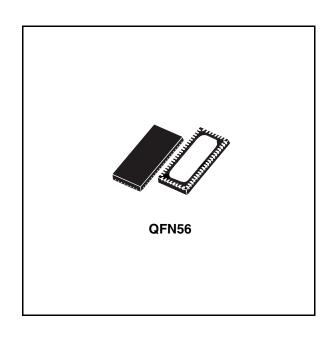
■ Package: QFN56

■ Pb-free

### **Applications**

■ 10/100/1000 Mbit Ethernet switching

Audio/video switching



#### **Description**

The STMUX1800L is a 16- to 8-bit multiplexer/demultiplexer low  $R_{ON}$  bidirectional LAN switch designed for various standards, such as 10/100/1000 Ethernet. It is designed for very low crosstalk, low bit-to-bit skew and low I/O capacitance.

The differential signal from the Gigabit Ethernet transceiver is multiplexed into one of two selected outputs while the unselected switch goes to Hi-Z status.

The device integrates three SPDT (single pole dual throw) switches, for LED support.

Table 1. Device summary

Order code	Package	Packing
STMUX1800LQTR	QFN56	Tape and reel

Contents STMUX1800L

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STMUX1800L Pin description

## 1 Pin description

Figure 1. Pin connection (top through view)

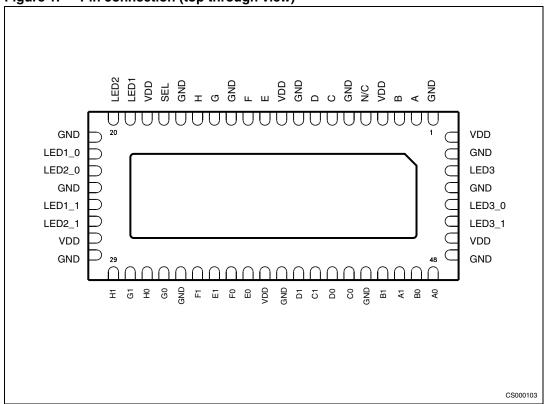


Table 2. Pin description

Pin	Symbol	Name and function
2, 3, 7, 8, 11, 12, 14, 15	A, B, C, D, E, F, G, H	8-bit bus
48, 47, 43, 42, 37, 36, 32, 31	A0, B0, C0, D0, E0, F0, G0, H0	8-bit multiplexed to bus 0
46, 45, 41, 40, 35, 34, 30, 29	A1, B1, C1, D1, E1, F1, G1, H1	8-bit multiplexed to bus 1
5	N/C	Not connected
17	SEL	Bus and LED switch selection
19, 20, 54	LED1, LED2, LED3	LED switch input
22, 23, 25, 26, 51, 52	LED1_0, LED2_0, LED1_1, LED2_1, LED3_1, LED3_0	LED switch output
4, 10, 18, 27, 38, 50, 56	V <sub>DD</sub>	Supply voltage
1, 6, 9, 13, 16, 21, 24, 28, 33, 39, 44, 49, 53, 55	GND	Ground

Pin description STMUX1800L

Figure 2. Input equivalent circuit

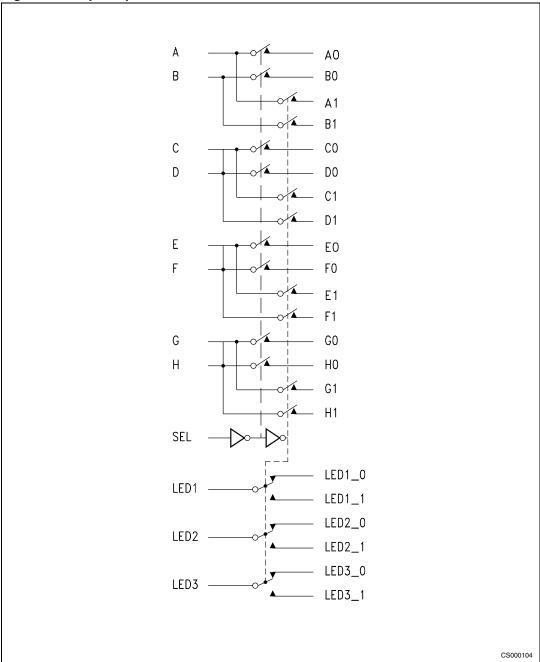


Table 3. LAN switch function table

SEL	Function
L	8-bit bus to 8-bit multiplexed bus 0
Н	8-bit bus to 8-bit multiplexed bus 1

STMUX1800L Pin description

Table 4. LED switch function table

SEL Function			
L	LED switch input connected to LED switch output X_0		
Н	LED switch input connected to LED switch output X_1		

Maximum ratings STMUX1800L

## 2 Maximum ratings

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 5. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage to ground	-0.5 to 4.6	V
V <sub>IO</sub>	DC input output voltage	-0.5 to 4.6	V
V <sub>IC</sub>	DC control input voltage	-0.5 to 4.6	V
Io	DC output current <sup>(1)</sup>	120	mA
P <sub>D</sub>	Power dissipation	0.5	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
T <sub>L</sub>	Lead temperature (10 sec)	300	°C

<sup>1.</sup> If V<sub>IO</sub> x I<sub>O</sub> does not exceed the maximum limit of P<sub>D</sub>.

### 2.1 Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter		Unit		
	Parameter	Min	Тур	Max	Oiiit
V <sub>CC</sub>	Supply voltage to ground	3	-	3.6	V
V <sub>IC</sub>	DC control input voltage (SEL)	0	_	5	V
V <sub>IO</sub>	DC input/output voltage	0	_	V <sub>CC</sub>	V
T <sub>A</sub>	Operating temperature	-40	1	85	°C

## 3 Electrical characteristics

Table 7. DC electrical characteristics for Gigabit Ethernet LAN8/16MUX/DEMUX  $(V_{CC} = 3.3 \text{ V} \pm 10\%)$ 

				Value		
Symbol	Parameter	Test condition	,	-40 to 85 °C	;	Unit
			Min	Тур	Max	
V <sub>IH</sub>	Voltage input high (SEL)	High level guaranteed	2	-	-	V
V <sub>IL</sub>	Voltage input low (SEL)	Low level guaranteed	-0.5	_	0.8	٧
$V_{IK}$	Clamp diode voltage (SEL)	$V_{CC} = 3.6 \text{ V}$ $I_{IN} = -18 \text{ mA}$	_	-0.8	-1.2	V
I <sub>IH</sub>	Input high current (SEL)	$V_{CC} = 3.6 \text{ V}$ $V_{IN} = V_{CC}$	_	_	±5	μΑ
I <sub>IL</sub>	Input low current (SEL)	$V_{CC} = 3.6 \text{ V}$ $V_{IN} = \text{GND}$	-	_	±5	μA
IOFF <sub>(SW)</sub> <sup>(1)</sup>	Leakage current through the switch common terminals (A to H) (LED1 to LED3)	$V_{CC} = 3.6 \text{ V}$ A to H = $V_{CC}$ LED1 to LED3 = $V_{CC}$ A0 to H0 = 0 V A1 to H1 = floating LEDx_0 = 0 V LEDx1 = floating SEL = $V_{CC}$	_	_	±1	μА
IOFF <sub>(SEL)</sub>	SEL pin leakage current	V <sub>CC</sub> = 0 V SEL = 0 to 3.6 V	_	_	±1	μΑ
R <sub>ON</sub>	Switch ON resistance <sup>(2)</sup>	$V_{CC}$ = 3.0 V $V_{IN}$ = 1.5 to $V_{CC}$ $I_{IN}$ = -40 mA	_	4.0	6.5	Ω
R <sub>FLAT</sub>	ON resistance flatness (2) (3)	$V_{CC} = 3.0 \text{ V}$ $V_{IN}$ at 1.5 and VCC $I_{IN} = -40 \text{ mA}$	_	0.5	_	Ω
$\Delta R_{ON}$	ON resistance match between channel $ \Delta R_{ON} = R_{ONMAX} - R_{ONMIN} $	$V_{CC} = 3.0 \text{ V}$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{ mA}$	-	0.4	1	Ω

<sup>1.</sup> Refer to Figure 4: Test circuit for leakage current (IOFF) on page 11

<sup>2.</sup> Measured by voltage drop between channels at indicated current through the switch. ON resistance is determined by the lower of the voltages.

<sup>3.</sup> Flatness is defined as the difference between the  $R_{ONMAX}$  and  $R_{ONMIN}$  of ON resistance over the specified range.

<sup>4.</sup>  $\Delta R_{ON}$  measured at same  $V_{CC},$  temperature and voltage level.

Table 8. DC electrical characteristics for 10/100 Ethernet LAN8/16MUX/DEMUX ( $V_{CC} = 3.3 \text{ V} \pm 10$ )

Symbol	Parameter	Test condition	-40 to 85 °C			Unit
			Min	Тур	Max	
V <sub>IH</sub>	Voltage input high (SEL)	High level guaranteed	2	-	-	V
V <sub>IL</sub>	Voltage input low (SEL)	Low level guaranteed	-0.5	-	0.8	V
V <sub>IK</sub>	Clamp diode voltage (SEL)	V <sub>CC</sub> = 3.6 V I <sub>IN</sub> = -18 mA	-	-0.7	-1.2	V
I <sub>IH</sub>	Input high current (SEL)	$V_{CC} = 3.6 \text{ V}$ $V_{IN} = V_{CC}$	-	-	±5	μΑ
I <sub>IL</sub>	Input low current (SEL)	V <sub>CC</sub> = 3.6 V V <sub>IN</sub> = GND	-	-	±5	μΑ
IOFF <sub>(SW)</sub> <sup>(1)</sup>	Leakage current through the switch common terminals (A to H) (LED1 to LED3)	$V_{CC} = 3.6 \text{ V}$ A to H = $V_{CC}$ LED1 to LED3 = $V_{CC}$ A0 to H0 = 0 V A1 to H1 = floating LEDx_0 = 0 V LEDx1 = floating SEL = $V_{CC}$	-	-	±1	μΑ
IOFF <sub>(SEL)</sub>	SEL pin leakage current	V <sub>CC</sub> = 0 V SEL = 0 to 3.6 V	-	1	±1	μΑ
R <sub>ON</sub>	Switch ON resistance <sup>(2)</sup>	$V_{CC} = 3.0 \text{ V}$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -10 \text{ to } -30 \text{ mA}$	_	4.0	6.5	Ω
R <sub>FLAT</sub>	ON resistance flatness (2) (3)	$V_{CC} = 3.0 \text{ V}$ $V_{IN}$ at 1.5 and $V_{CC}$ $I_{IN} = -10 \text{ to } -30 \text{ mA}$	_	0.5	_	Ω
$\Delta R_{ ext{ON}}$	ON resistance match between channel $ \Delta R_{ON} = R_{ONMAX} - R_{ONMIN}^{(2)(4)} $	$V_{CC} = 3.0 \text{ V}$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -10 \text{ to } -30 \text{ mA}$	-	0.4	1	Ω

<sup>1.</sup> Refer to Figure 4: Test circuit for leakage current (IOFF) on page 11

Measured by voltage drop between channels at indicated current through the switch. ON resistance is determinate by the lower of the two voltages.

<sup>3.</sup> Flatness is defined as the difference between the  $R_{ONMAX}$  and  $R_{ONMIN}$  of ON resistance over the specified range.

<sup>4.</sup>  $\Delta \rm R_{ON}$  measured at same  $\rm V_{CC},$  temperature and voltage level.

Table 9. Capacitance ( $T_A = 25$  °C, f = 1 MHz)

Symbol	Parameter	Test condition	Value			Unit
	Parameter	rest condition	Min	Тур	Max	Offic
C <sub>IN</sub>	SEL pin input capacitance <sup>(1)</sup>	DC = 0.25 V AC = 0.5 V <sub>PP</sub> f = 1 MHz	-	2	3	pF
C <sub>OFF</sub>	Switch off capacitance <sup>(2)</sup>	DC = 0.25 V AC = 0.5 V <sub>PP</sub> f = 1 MHz	-	4	5	pF
C <sub>ON</sub>	Switch on capacitance <sup>(3)</sup>	DC = 0.25 V AC = 0.5 V <sub>PP</sub> f = 1 MHz	-	9.5	11	pF

- 1. Refer to Figure 5 on page 12
- 2. Refer to Figure 6 on page 12
- 3. Refer to Figure 7 on page 13

Table 10. Power supply characteristics

Symbol	Parameter	Test condition	-	40 to 85 °C	<b>;</b>	Unit
			Min	Тур	Max	
I <sub>CC</sub>	Quiescent power supply	$V_{CC} = 3.6 \text{ V}, V_{IN} = V_{CC} \text{ or }$ GND	_	150	500	μΑ

Table 11. Dynamic electrical characteristics ( $V_{CC} = 3.3 \text{ V} \pm 10\%$ )

	_					
Symbol	Parameter	Test condition	-	40 to 85 °C	;	Unit
			Min	Тур	Max	
X <sub>talk</sub>	Crosstalk <sup>(1)</sup>	$R_L$ = 100 $Ω$ f = 250 MHz	-	-45	-	dB
O <sub>IRR</sub>	Off isolation <sup>(2)</sup>	$R_L$ = 100 Ω f = 250 MHz	_	-37	_	dB
BW	-3 dB bandwidth <sup>(3)</sup>	$R_L$ = 100 Ω $0 < V_{IN} \le 3.6 V$	_	600	ı	MHz

- 1. Refer to Figure 9 on page 14
- 2. Refer to Figure 10 on page 15
- 3. Refer to Figure 8 on page 13

Table 12. Switching characteristics ( $T_A = 25$  °C,  $V_{CC} = 3.3$  V ±10%)

Symbol	Parameter	Test condition	Value			Unit
			Min	Тур	Max	Offic
t <sub>PD</sub>	Propagation delay	$V_{CC} = 3 \text{ to } 3.6 \text{ V}$	_	0.25	1	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	Line enable time, SE to x to x0 or x to x1	V <sub>CC</sub> = 3 to 3.6 V	0.5	6.5	15	ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Line disable time, SE to x to x0 or x to x1	$V_{CC} = 3 \text{ to } 3.6 \text{ V}$	0.5	6.5	8.5	ns
t <sub>SK(O)</sub>	Output skew between center port to any other port	V <sub>CC</sub> = 3 to 3.6 V	_	0.1	0.2	ns
t <sub>SK(P)</sub>	Skew between opposite transition of the same output (t <sub>PHL</sub> , t <sub>PLH</sub> )	V <sub>CC</sub> = 3 to 3.6 V	-	0.1	0.2	ns

Table 13. ESD performance

Symbol	Test condition	Value			Unit
	rest condition	Min	Тур	Max	
ESD	Contact discharge <sup>(1)</sup> IEC61000-4-2	_	±8	_	kV
	Human body model (MIL-STD-883)	ı	±15	ı	kV

<sup>1.</sup> Refer to Figure 3: Diagram for suggested VDD decoupling on page 11.

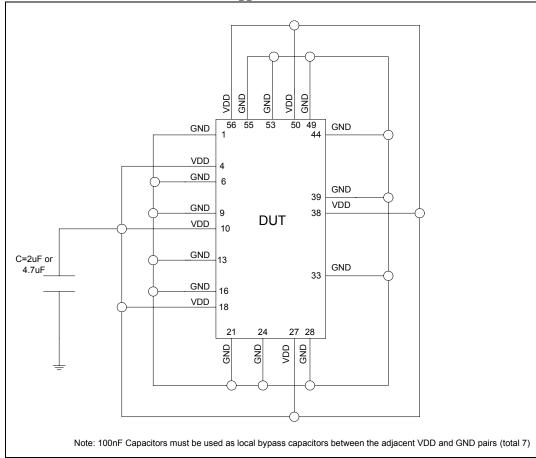
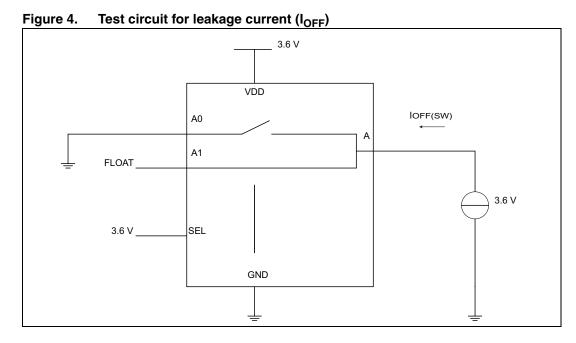


Figure 3. Diagram for suggested  $V_{DD}$  decoupling

1. Applicable for system level ESD test



3.3 V

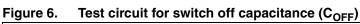
LCR meter
DC = 0.25 V
AC = 0.5 Vpp
f = 1 MHz

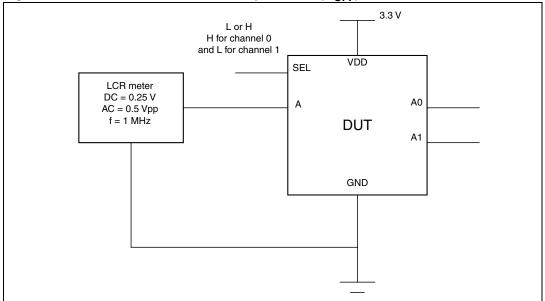
SEL

DUT

GND

Figure 5. Test circuit for SEL pin input capacitance (C<sub>IN</sub>)





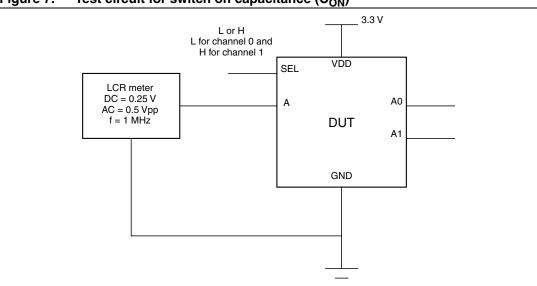
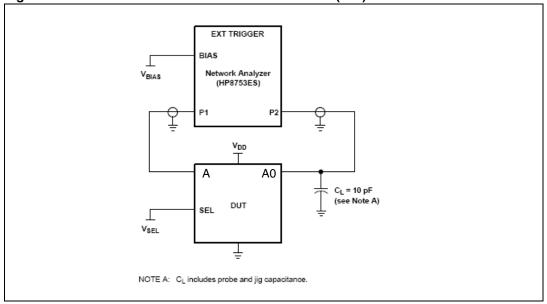


Figure 7. Test circuit for switch on capacitance (C<sub>ON</sub>)

Figure 8. Test circuit for bandwidth measurement (BW)



Frequency response is measured at the output of the ON channel. For example, when  $V_{SEL} = 0$  and A is the input, the output is measured at A0. All unused analog I/O ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$ 

 $V_{BIAS} = 0.35 V$ 

ST = 2 s

P1 = 0 dBm

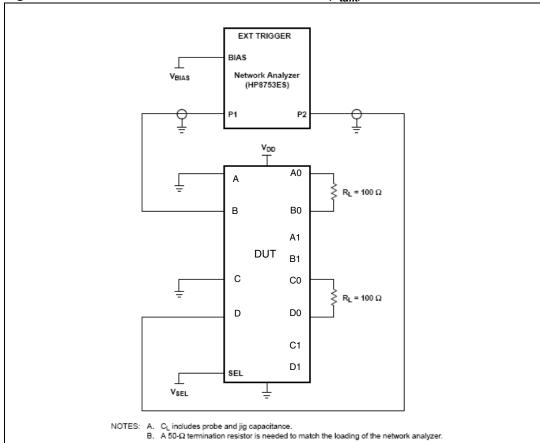


Figure 9. Test circuit for crosstalk measurement (x<sub>talk</sub>)

Crosstalk is measured at the output of the non-adjacent ON channel. For example, when  $V_{SEL} = 0$ , and B is the input, the output is measured at D. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$ 

 $V_{BIAS} = 0.35 V$ 

ST = 2 s

P1 = 0 dBm

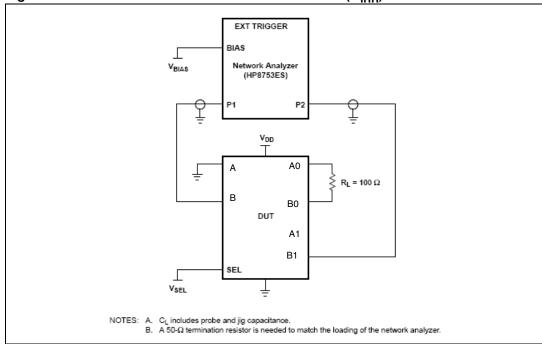


Figure 10. Test circuit for off isolation measurement (OIRR)

Off isolation is measured at the output of the OFF channel. For example, when  $V_{SEL}$ =0, and B is the input, the output is measured at B1. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$ 

 $V_{BIAS} = 0.35 V$ 

ST = 2 s

P1 = 0 dBm

## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

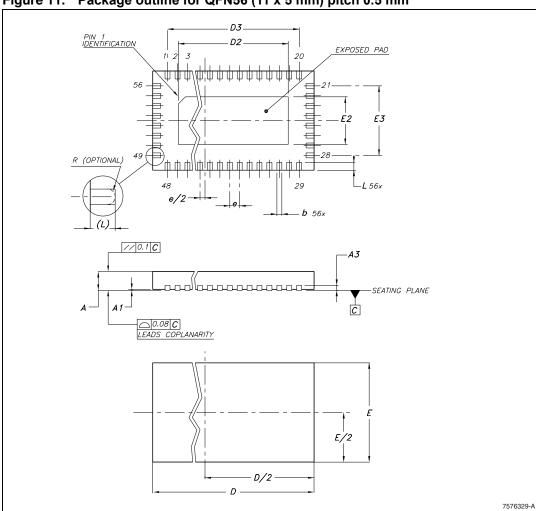
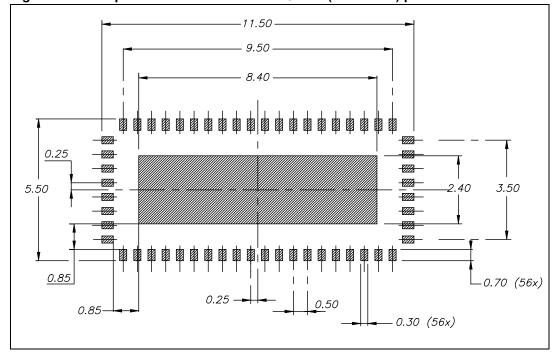


Figure 11. Package outline for QFN56 (11 x 5 mm) pitch 0.5 mm

Figure 12. Mechanical data for QFN56 (11 x 5 mm) pitch 0.5 mm

Symbol	Millimeters				
Symbol	Min	Тур	Max		
А	0.70	0.75	0.80		
A1	-	-	0.05		
А3		0.20	-		
b	0.20	0.25	0.30		
D	10.90	11.00	11.10		
D2	8.30	8.40	8.50		
D3	-	9.50	-		
E	4.90	5.00	5.10		
E2	2.30	2.40	2.50		
E3	_	3.50	-		
е	-	0.50	-		
L	0.30	0.40	0.50		

Figure 13. Footprint recommendation for QFN56 (11 x 5 mm) pitch 0.5 mm



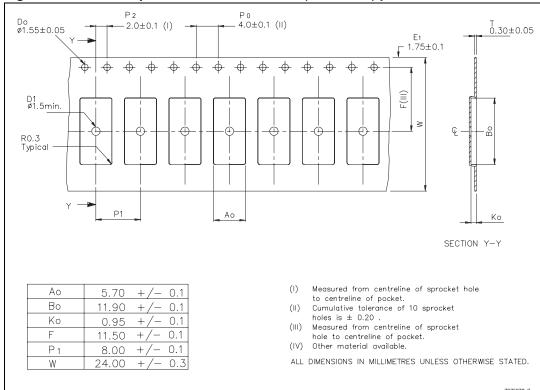


Figure 14. Carrier tape information for QFN56 (11 x 5 mm) pitch 0.5 mm

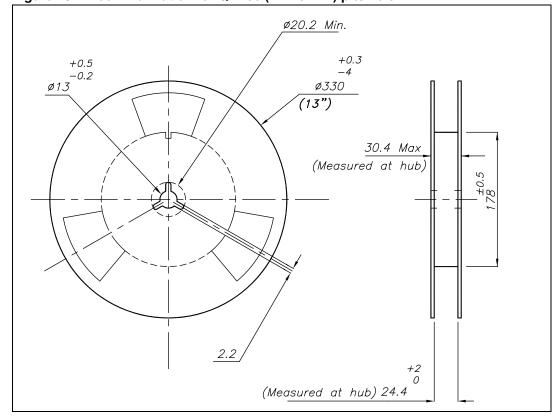


Figure 15. Reel information for QFN56 (11 x 5 mm) pitch 0.5 mm

Revision history STMUX1800L

# 5 Revision history

Table 14. Document revision history

Date	Revision	Changes
26-Feb-2008	1	Initial release.
24-Sep-2008	2	Modified: datasheet title, channel on capacitance value from 7.5 pF to 9.5 pF typical, <i>Figure 1</i> , <i>Table 2</i> , <i>Section 3: Electrical characteristics</i> .  Added: fields of applications, <i>Table 6</i> and QFN56 footprint recommendations in <i>Figure 13 on page 17</i> .
30-Mar-2009	3	Updated: Features section, <i>Table 5 on page 6</i> , <i>Table 11 on page 9</i> and <i>Table 13 on page 10</i> and <i>Chapter 4: Package mechanical data</i> .
22-Jun-2009	4	Document promoted from Preliminary data to datasheet.

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COMX-CAR-210 5962-8607001EA MAX3783UCM+D PI5C3253QEX 8CA3052APGGI8 TC74HC4051AF(EL,F) TC74VHC138F(EL,K,F
PI3B3251LE PI5C3251QEX PI3B3251QE 74VHC4052AFT(BJ) PI3PCIE3415AZHEX NLV74HC4851AMNTWG MC74LVX257DG
M74HC151YRM13TR M74HC151YTTR PI5USB31213XEAEX M74HCT4851ADWR2G XD74LS154 AP4373AW5-7-01
MC74HC151ADTG 74ACT11139PWR QS3VH251QG8 QS4A201QG HCS500-I/SM TC4066BP(N,F) 74VHC238FT(BJ)
74VHC4066AFT(BJ) 74VHCT138AFT(BJ) 74HC158D.652 74HC4052D(BJ) 74VHC138MTC COMX-CAR-P1 JM38510/36001BEA
JM38510/30702BEA PI3USB302-AZBEX PI5C3257LE